



# NHDTC144EU-Q

80 V, 100 mA NPN resistor-equipped transistor

9 August 2023

Product data sheet

## 1. General description

NPN Resistor-Equipped Transistor (RET) in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package.

## 2. Features and benefits

- 100 mA output current capability
- High breakdown voltage
- Built-in resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- Qualified according to AEC-Q101 and recommended for use in automotive applications

## 3. Applications

- Digital applications
- Cost saving alternative for BC846 series in digital applications
- Controlling IC inputs
- Switching loads

## 4. Quick reference data

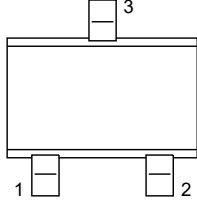
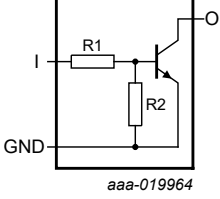
Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base		-	-	80	V
$I_O$	output current			-	-	100	mA
R1	bias resistor 1 (input)	$T_{amb} = 25\text{ }^{\circ}\text{C}$	[1]	33	47	61	k $\Omega$
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	

[1] See section "Test information" for resistor calculation and test conditions

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)	 <p>SC-70 (SOT323)</p>	 <p>aaa-019964</p>
2	G	GND (emitter)		
3	O	output (collector)		

## 6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
<a href="#">NHDTC144EU-Q</a>	SC-70	plastic, surface-mounted package; 3 leads; 1.3 mm pitch; 2 mm x 1.25 mm x 0.95 mm body	<a href="#">SOT323</a>

## 7. Marking

Table 4. Marking codes

Type number	Marking code[1]
NHDTC144EU-Q	5S%

[1] % = placeholder for manufacturing site code

## 8. Limiting values

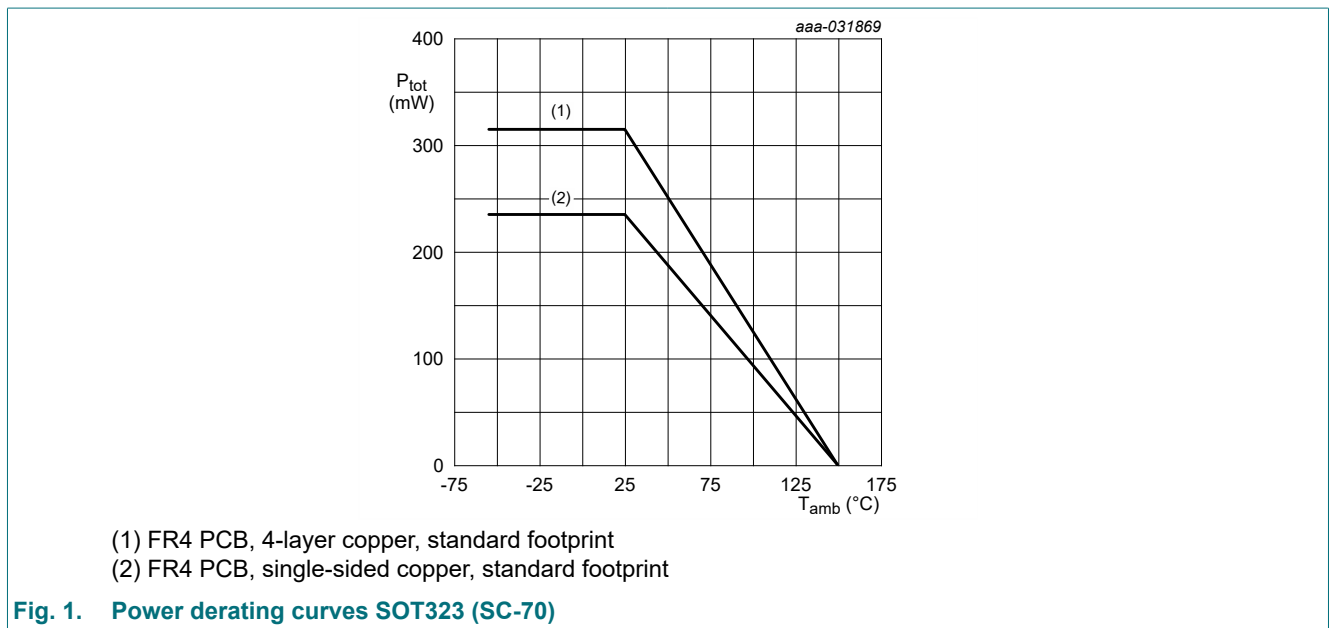
**Table 5. Limiting values**

$T_{amb} = 25\text{ °C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Max	Unit	
$V_{CBO}$	collector-base voltage	open emitter	-	80	V	
$V_{CEO}$	collector-emitter voltage	open base	-	80	V	
$V_{EBO}$	emitter-base voltage	open collector	-	10	V	
$V_I$	input voltage		-10	80	V	
$I_O$	output current		-	100	mA	
$P_{tot}$	total power dissipation	$T_{amb} \leq 25\text{ °C}$	[1]	-	235	mW
			[2]	-	315	mW
$T_j$	junction temperature		-	150	°C	
$T_{amb}$	ambient temperature		-55	150	°C	
$T_{stg}$	storage temperature		-65	150	°C	

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB), single-sided copper, tin-plated and standard footprint

[2] Device mounted on an FR4 (PCB);4-layer copper, tin-plated and standard footprint.



### 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	532	K/W
			[2]	-	-	397	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	-	150	K/W

- [1] Device mounted on an FR4 (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 (PCB), 4-layer copper, tin-plated and standard footprint.

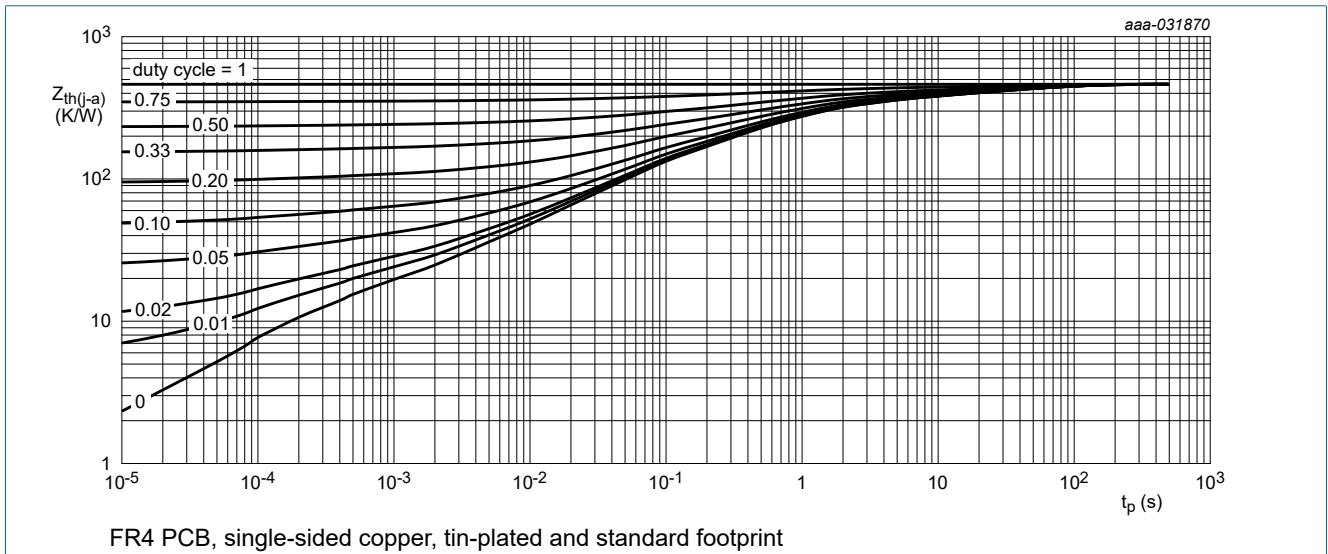


Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

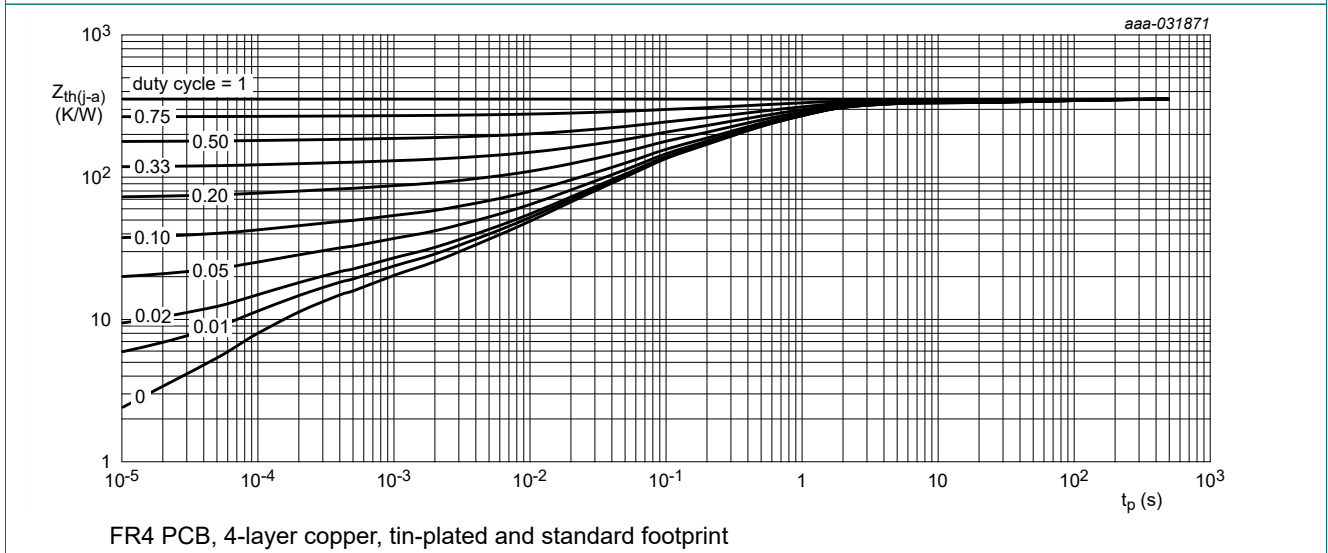


Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

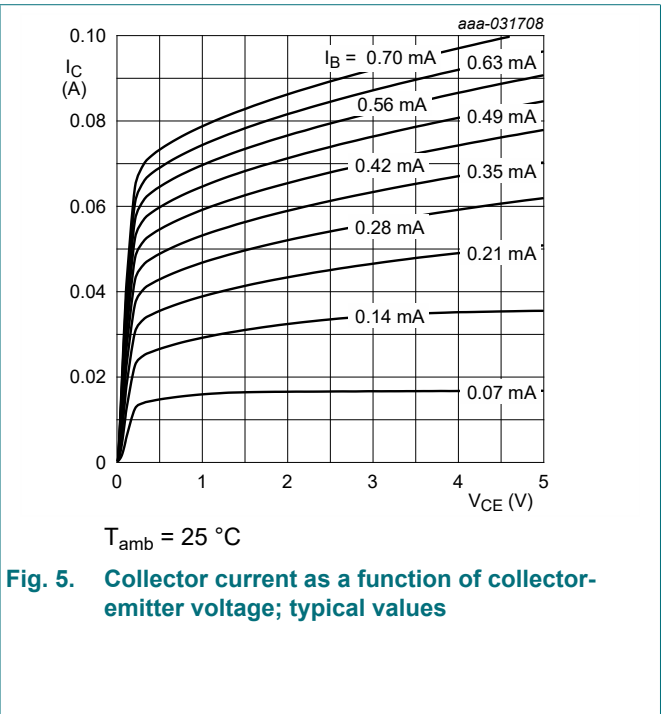
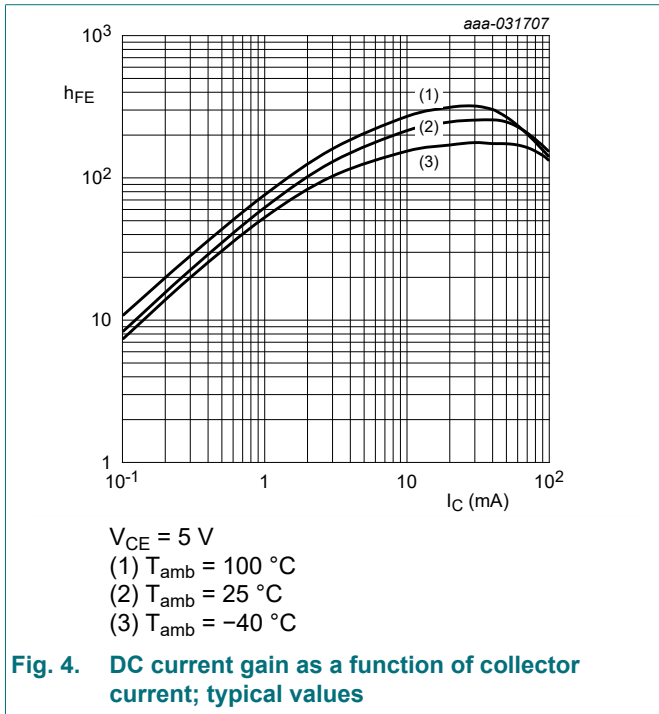
## 10. Characteristics

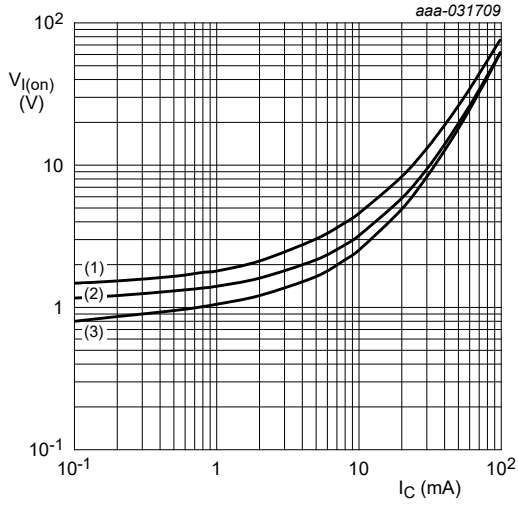
Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 100 \mu\text{A}$ ; $I_E = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	80	-	-	V	
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}$ ; $I_B = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	80	-	-	V	
$I_{CBO}$	collector-base cut-off current	$V_{CB} = 80 \text{ V}$ ; $I_E = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	100	nA	
$I_{CEO}$	collector-emitter cut-off current	$V_{CE} = 60 \text{ V}$ ; $I_B = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	100	nA	
		$V_{CE} = 60 \text{ V}$ ; $I_B = 0 \text{ A}$ ; $T_j = 150 \text{ }^\circ\text{C}$	-	-	5	$\mu\text{A}$	
$I_{EBO}$	emitter-base cut-off current	$V_{EB} = 7 \text{ V}$ ; $I_C = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	130	$\mu\text{A}$	
$h_{FE}$	DC current gain	$V_{CE} = 5 \text{ V}$ ; $I_C = 10 \text{ mA}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	100	-	-		
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 10 \text{ mA}$ ; $I_B = 0.5 \text{ mA}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	100	mV	
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5 \text{ V}$ ; $I_C = 100 \mu\text{A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	1.15	0.8	V	
$V_{I(on)}$	on-state input voltage	$V_{CE} = 0.3 \text{ V}$ ; $I_C = 10 \text{ mA}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	5	3.3	-	V	
R1	bias resistor 1 (input)	$T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	[1]	33	47	61	k $\Omega$
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	
$C_c$	collector capacitance	$V_{CB} = 10 \text{ V}$ ; $I_E = 0 \text{ A}$ ; $i_e = 0 \text{ A}$ ; $f = 1 \text{ MHz}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	2.5	pF	
$f_T$	transition frequency	$V_{CE} = 5 \text{ V}$ ; $I_C = 10 \text{ mA}$ ; $f = 100 \text{ MHz}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	[2]	170	-	MHz	

[1] See section "Test information" for resistor calculation and test conditions

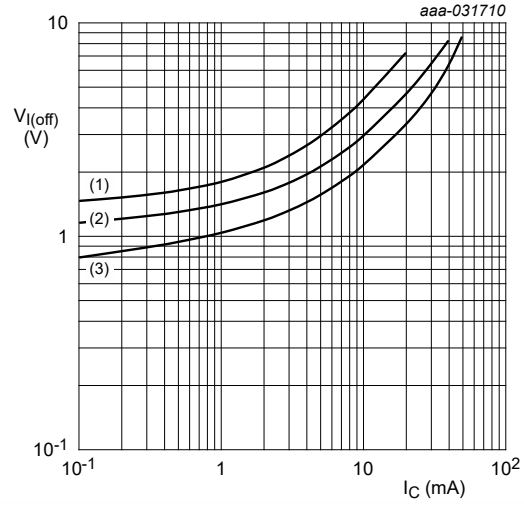
[2] Characteristics of built-in transistor





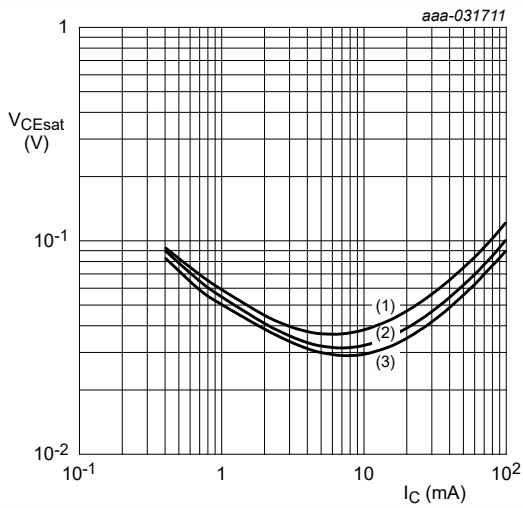
$V_{CE} = 0.3$  V  
 (1)  $T_{amb} = -40$  °C  
 (2)  $T_{amb} = 25$  °C  
 (3)  $T_{amb} = 100$  °C

**Fig. 6. On-state input voltage as a function of collector current; typical values**



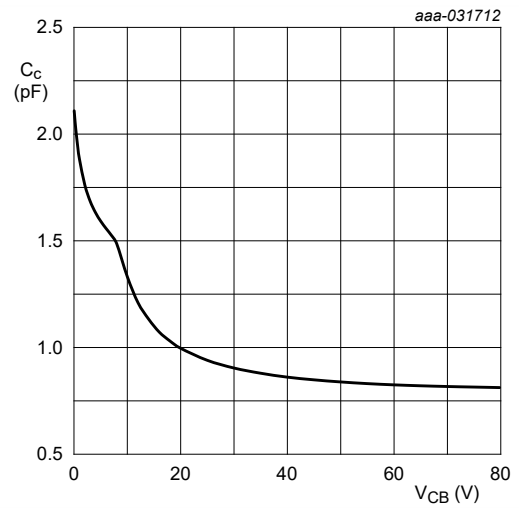
$V_{CE} = 5$  V  
 (1)  $T_{amb} = -40$  °C  
 (2)  $T_{amb} = 25$  °C  
 (3)  $T_{amb} = 100$  °C

**Fig. 7. Off-state input voltage as a function of collector current; typical values**



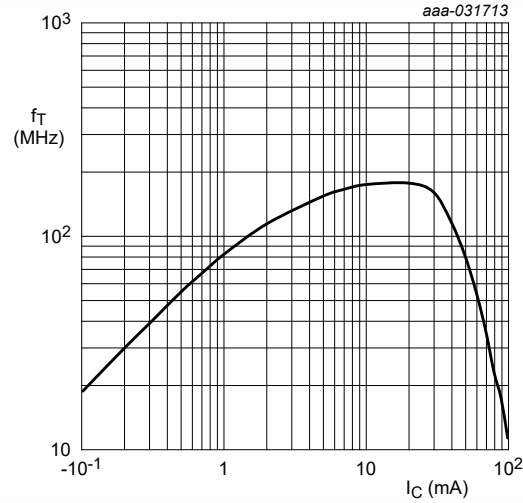
$I_C/I_B = 20$   
 (1)  $T_{amb} = 100$  °C  
 (2)  $T_{amb} = 25$  °C  
 (3)  $T_{amb} = -40$  °C

**Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values**



$f = 1$  MHz  
 $T_{amb} = 25$  °C

**Fig. 9. Collector capacitance as a function of collector-base voltage; typical values**



$f = 100 \text{ MHz}; V_{CE} = 5 \text{ V } T_{amb} = 25 \text{ }^\circ\text{C}$

**Fig. 10. Transition frequency as a function of collector current; typical values of built-in transistor**

## 11. Test information

### Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

### Resistor calculation

- Calculation of bias resistor 1 (R1):

$$R_1 = \frac{V(I_2) - V(I_1)}{I_2 - I_1}$$

- Calculation of bias resistor ratio (R2/R1):

$$\frac{R_2}{R_1} = \frac{V(I_4) - V(I_3)}{R_1 \cdot (I_4 - I_3)} - 1$$

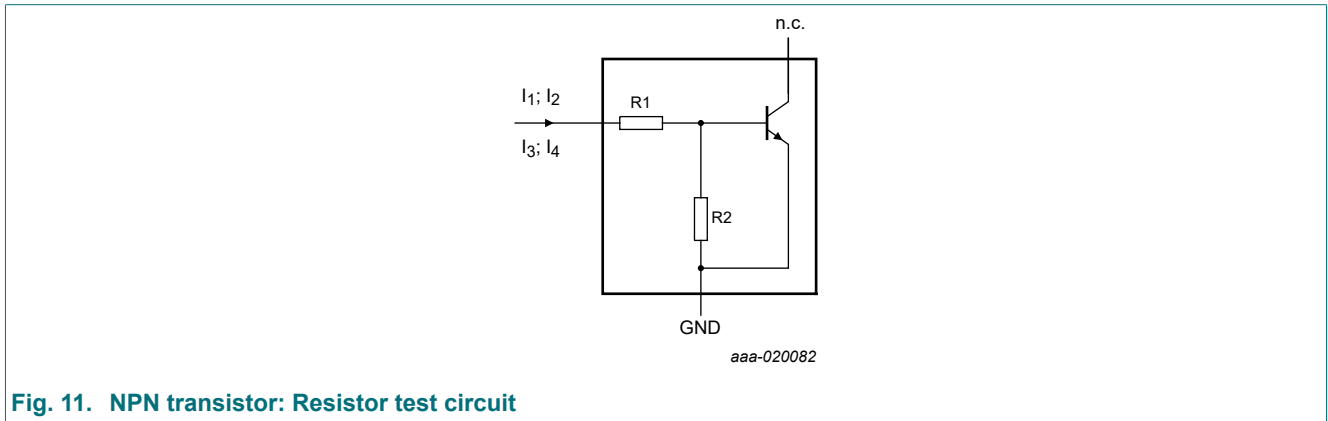


Fig. 11. NPN transistor: Resistor test circuit

### Resistor test conditions

Table 8. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I <sub>1</sub>	I <sub>2</sub>	I <sub>3</sub>	I <sub>4</sub>
NHDTC144EU-Q	47	47	250 μA	350 μA	-55 μA	-105 μA



## 12. Package outline

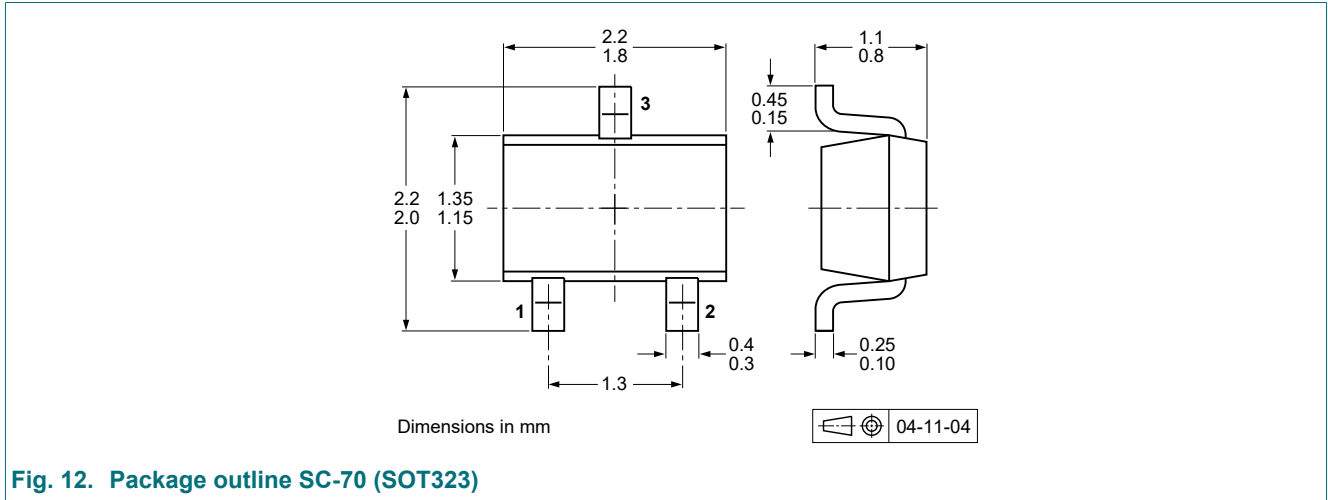


Fig. 12. Package outline SC-70 (SOT323)

## 13. Soldering

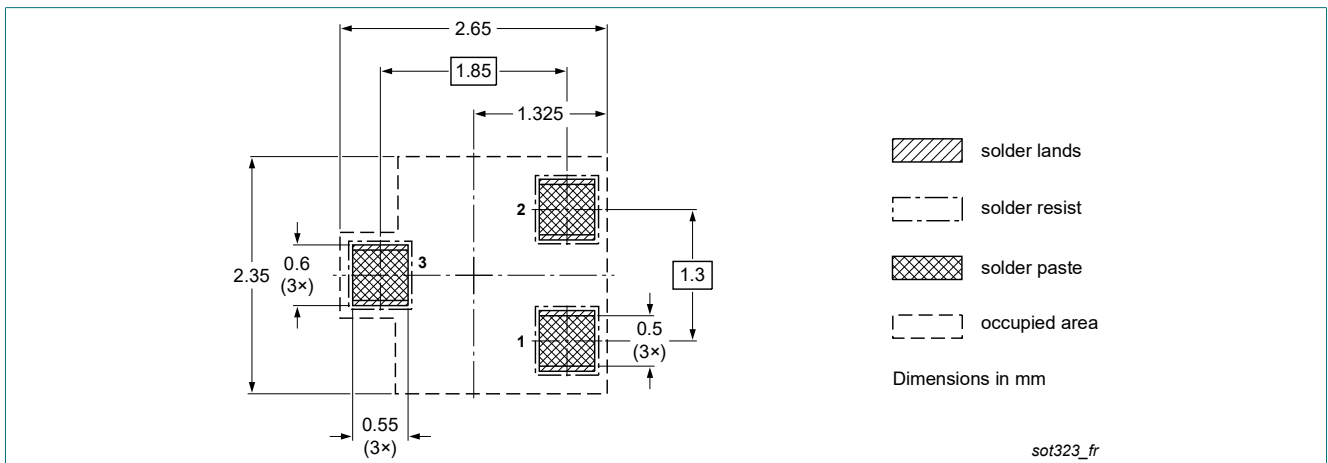


Fig. 13. Reflow soldering footprint for SC-70 (SOT323)

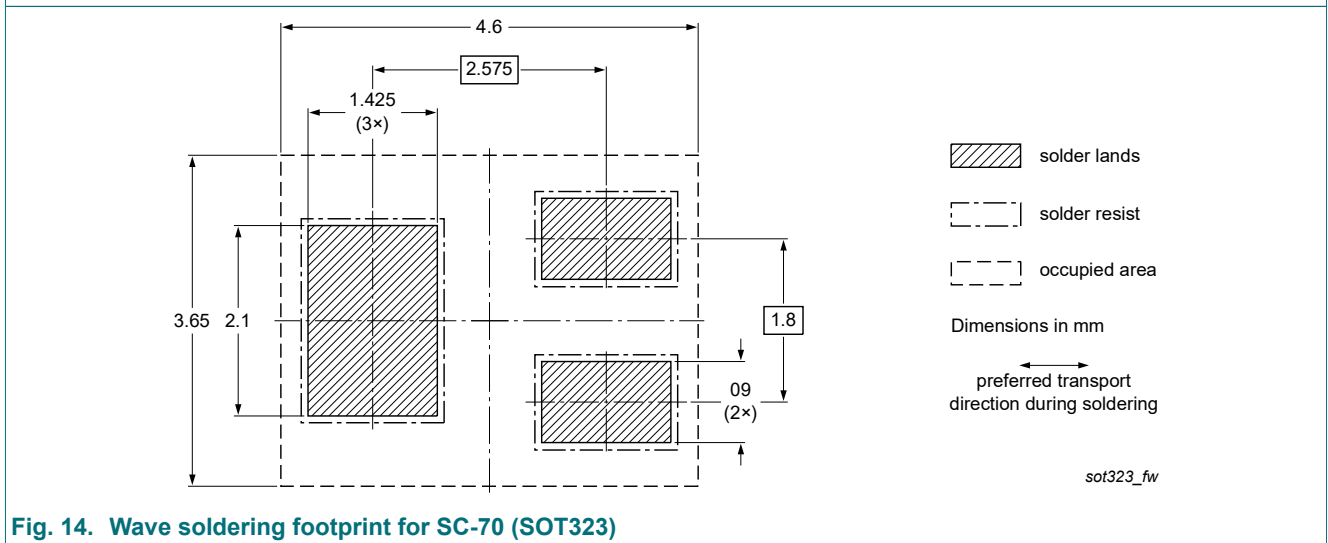


Fig. 14. Wave soldering footprint for SC-70 (SOT323)

### 14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
NHDTC144EU-Q v.1	20230809	Product data sheet	-	-

## 15. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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